

isc N-Channel MOSFET Transistor

2SK2116

DESCRIPTION

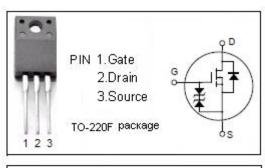
- Drain Current −I_D= 7A@ T_C=25°C
- · Drain Source Voltage-
- : V_{DSS}= 450V(Min)
- · Fast Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

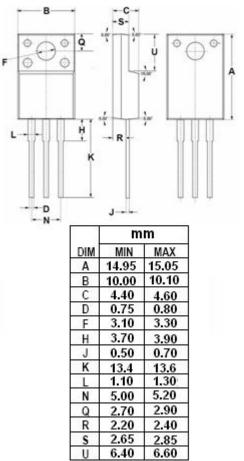
APPLICATIONS

Switching regulators

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL | ARAMETER | VALUE | UNIT |
|----------------------|-------------------------------------------|---------|------|
| V _{DSS} | Drain-Source Voltage (V _{GS} =0) | 450 | V |
| V _{GS} | Gate-Source Voltage | ±30 | V |
| ID | Drain Current-continuous@ TC=25℃ | | А |
| I _{D(puls)} | Pulsed Drain Current 28 | | A |
| P _{tot} | Total Dissipation@TC=25℃ | 35 | W |
| Tj | Max. Operating Junction Temperature | 150 | °C |
| T _{stg} | Storage Temperature Range | -55~150 | °C |





1



isc N-Channel MOSFET Transistor

2SK2116

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYPE | МАХ | UNIT |
|----------------------|---------------------------------|-----------------------------------------------------------------------|-----|------|-----|------|
| V _{(BR)DSS} | Drain-Source Breakdown Voltage | V _{GS} = 0; I _D = 10mA | 450 | | | V |
| $V_{GS(th)}$ | Gate Threshold Voltage | V _{DS} = 10V; I _D =1mA | 2.0 | | 3.0 | V |
| V_{SD} | Diode Forward On-voltage | I _S = 7.0A;V _{GS} = 0 | | 0.95 | | V |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} = 10V; I _D = 4.0A | | 0.6 | 0.8 | Ω |
| Igss | Gate-Body Leakage Current | V _{GS} = ±30V;V _{DS} = 0 | | | ±10 | μA |
| I _{DSS} | Zero Gate Voltage Drain Current | V _{DS} = 360V; V _{GS} = 0 | | | 250 | μA |
| Ciss | Input Capacitance | V _{DS} =10V; V _{GS} =0V; f _T =1MHz | | 1050 | | pF |
| Crss | Reverse Transfer Capacitance | | | 40 | | |
| Coss | Output Capacitance | | | 280 | | |
| tr | Rise Time | | | 55 | | |
| t d(on) | Turn-on Delay Time | I _D =4A; V _{DD} =10V; | | 15 | | |
| tſ | Fall Time | R _L =7.5 Ω | | 40 | | ns |
| td(off) | Turn-off Delay Time | | | 95 | | |

• ELECTRICAL CHARACTERISTICS (Tc=25°C)

NOTICE:

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications.

ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.

2

isc website: www.iscsemi.cn

isc & iscsemi is registered trademark